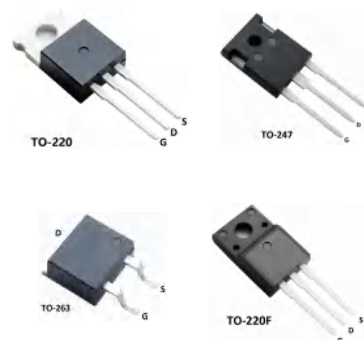


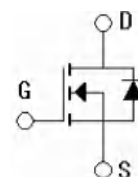
Features

- Low gate charge
- Low C_{RSS} (typ 13pF)
- Fast switchin
- 100% avalanche tested
- Improved dv/dt capability
- RoHS product



Applications

- High frequency switching mode power supply
- Electronic ballast based on half bridge
- LED power supplies



Absolute Ratings (Tc=25°C)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	1000	V
Drain Current-continuous	I_D T=25°C T=100°C	12	A
		8	A
Drain Current-pulse (note 1)	I_{DM}	64*	A
Gate-Source Voltage	V_{GS}	±30	V
Single pulse avalanche energy (note 2)	E_{AS}	858	mJ
Avalanche Current (note 1)	I_{AR}	12	A
Repetitive Avalanche Energy(note 1)	E_{AR}	27.7	mJ
Power Dissipation (SL12N100/T)	PD TC=25°C Derate above 25°C	272	W
		2.17	W/°C
Power Dissipation (SL12N100K)	PD TC=25°C Derate above 25°C	100	W
		0.8	W/°C
Power Dissipation (SL12N100F)	PD TC=25°C Derate above 25°C	68	W
		0.54	W/°C

Operating and Storage Temperature Range	T_J, T_{STG}	-55~+150	°C
Maximum Lead Temperature for Soldering Purposes	T_L	300	°C

*Drain current limited by maximum junction temperature

Electrical Characteristics($T_{CASE}=25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Tests conditions	Min	Type	Max	Units
Drain-Source Voltage	BV_{DSS}	$I_D=250\mu A, V_{GS}=0V$	1000	-	-	V
Breakdown Voltage Temperature Coefficient	$\Delta BV_{DSS}/\Delta T_J$	$I_D=250\mu A$, referenced to $25^{\circ}C$	-	0.98	-	V/°C
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=800V, V_{GS}=0V, T_C=25^{\circ}C$	-	-	1	μA
		$V_{DS}=720V, T_C=125^{\circ}C$	-	-	10	μA
Gate body leakage current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 30V$	-	-	± 100	nA
On-Characteristics						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	3.0	-	5.0	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=6A, T_C=25^{\circ}C$	-	1.0	1.2	Ω
Forward Transconductance	g_{FS}	$V_{DS}=40V, I_D=6A$ (note 4)	-	9.5	-	S
Dynamic Characteristics						
Input capacitance	C_{iss}	$V_{DS}=25V, V_{GS}=0V, f=1.0MHz$	-	2150	2830	pF
Output capacitance	C_{oss}		-	189	246	pF
Reverse transfer capacitance	C_{rss}		-	13	17	pF

Electrical Characteristics($T_{CASE}=25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Tests conditions	Min	Type	Max	Units
Switching-Characteristics						
Turn-On delay time	$t_{d(on)}$	$V_{DD}=600V, I_D=12A, R_{GEN}=25\Omega$ (note 4,5)	-	53	121	ns
Turn-On rise time	t_r		-	116	235	ns
Turn-Off delay time	$t_{d(off)}$		-	97	199	ns

Turn-Off rise time	t _f		-	69	171	ns
Total Gate Charge	Q _g	V _{DS} =800V,I _D =12A, V _{GS} =10V (note 4,5)	-	43	56	nC
Gate-Source charge	Q _{gs}		-	15	-	nC
Gate-Drain charge	Q _{gd}		-	21	-	nC
Drain-Source Diode Characteristics and Maximum Ratings						
Diode Forward Voltage (note 3)	V _{SD}	V _{GS} =0V,I _S =12A	-	-	1.4	V
Maximum Pulsed Drain-Source Diode Forward Current	I _{SM}	-	-	-	48	A
Maximum Continuous Drain Source Diode Forward Current	I _S	-	-	-	12	A
Reverse recovery time	t _{rr}	V _{GS} =0V,	-	539	-	ns
Reverse recovery charge	Q _{rr}	I _S =8A dI _F /dt=100A/μs (note 4)	-	6.41	-	μC

Thermal Characteristic

Parameter	Symbol	Value			Unit
		SL12N100 / T	SL12N100 K	SL12N100 F	
Thermal Resistance, junction to Case	$R_{th(j-C)}$	0.46	1.25	1.84	$^{\circ}C/W$
Thermal Resistance, Junction to Ambient	$R_{th(j-A)}$	40	62.5	62.5	$^{\circ}C/W$

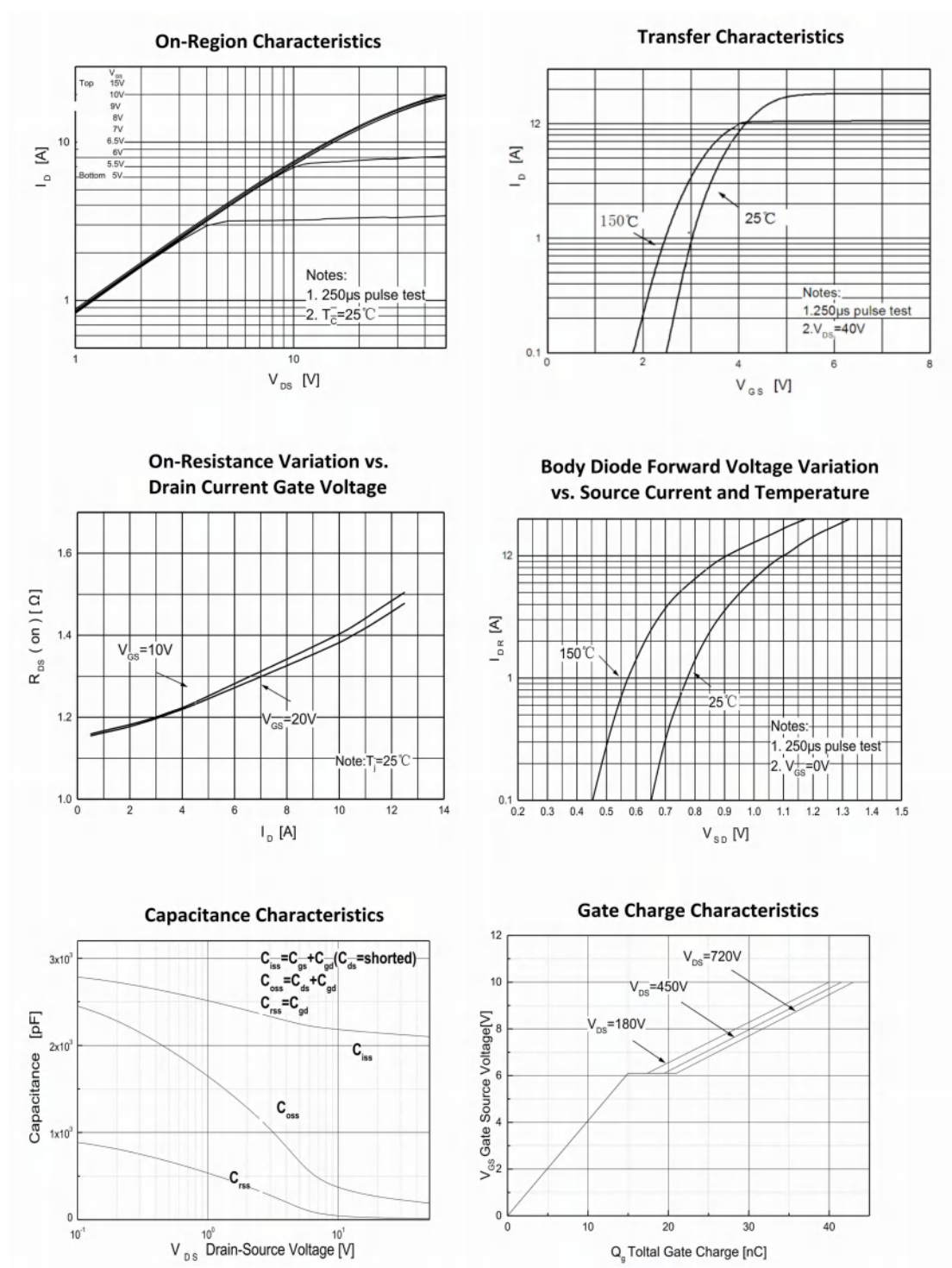
Order information

Order codes	Package	Packaging
SL12N100T	TO-247	Tube
SL12N100K	TO-263	Tube
SL12N100	TO-220	Tube
SL12N100F	TO-220F	Tube

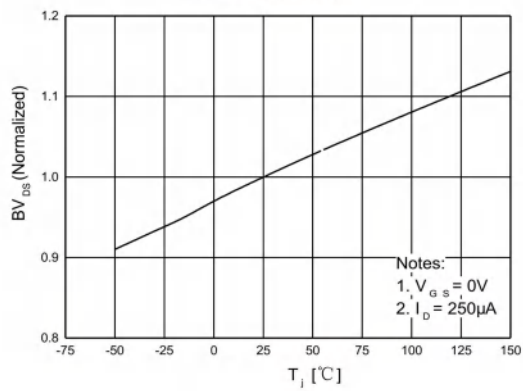
Notes:

1. Pulse width limited by maximum junction temperature
2. $L=20mH, I_{AS}=12A, V_{DD}=50V, R_G=25 \Omega$, Starting $T_J=25^{\circ}C$
3. $I_{SD} \leq 12A, di/dt \leq 300A/\mu s, V_{DD} \leq BV_{DSS}$, Starting $T_J=25^{\circ}C$
4. Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$
5. Essentially independent of operating temperature

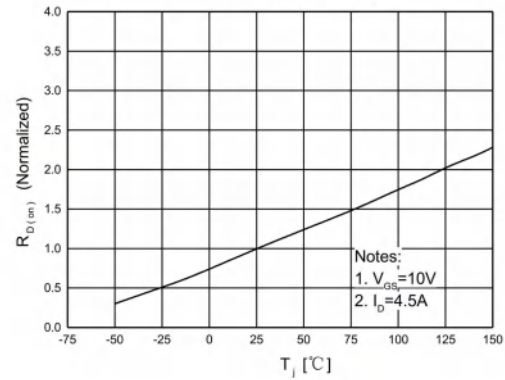
ELECTRICAL CHARACTERISTICS (curves)



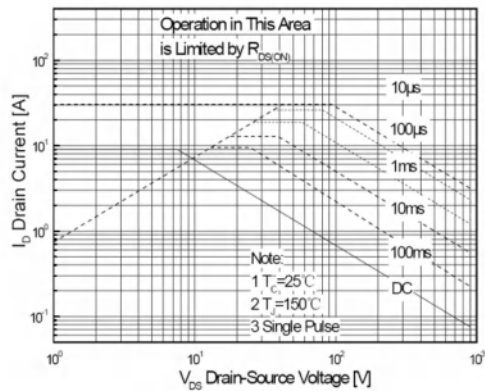
**Breakdown Voltage Variation
vs. Temperature**



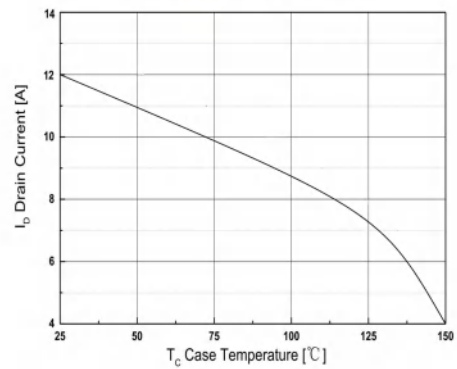
**On-Resistance Variation
vs. Temperature**



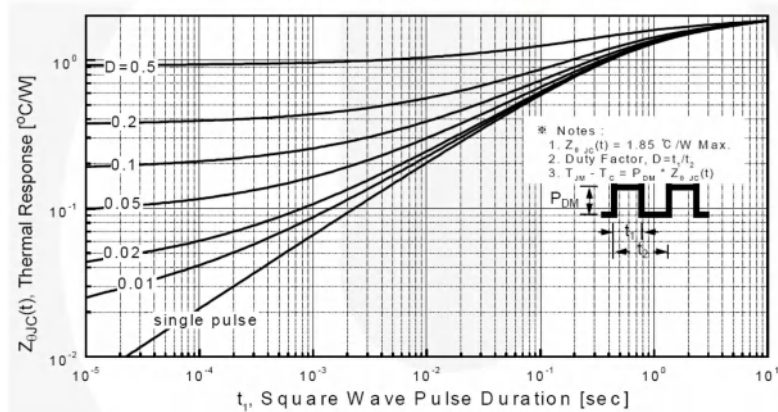
Maximum Safe Operating Area



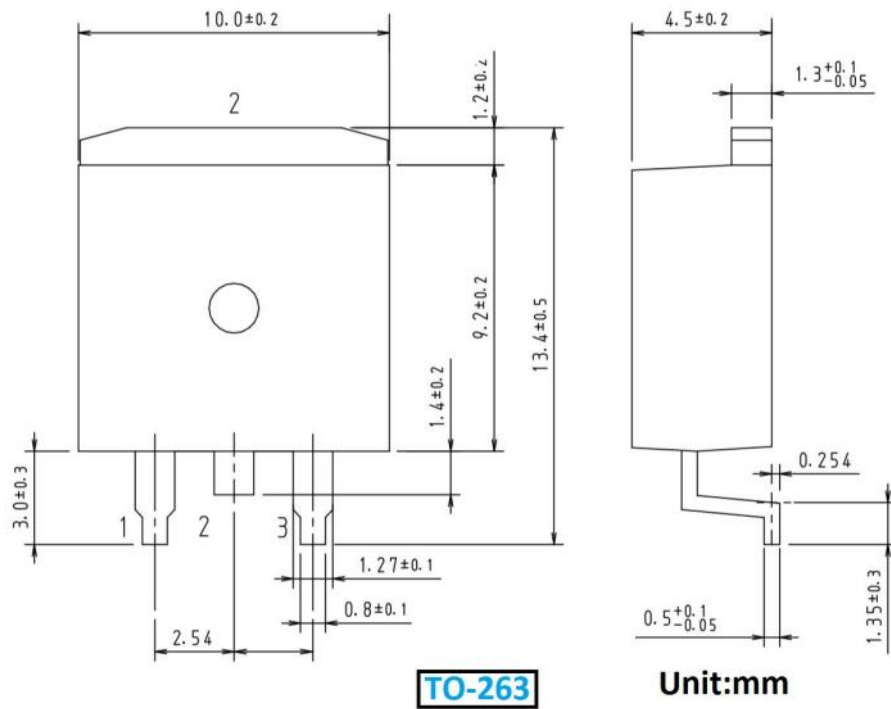
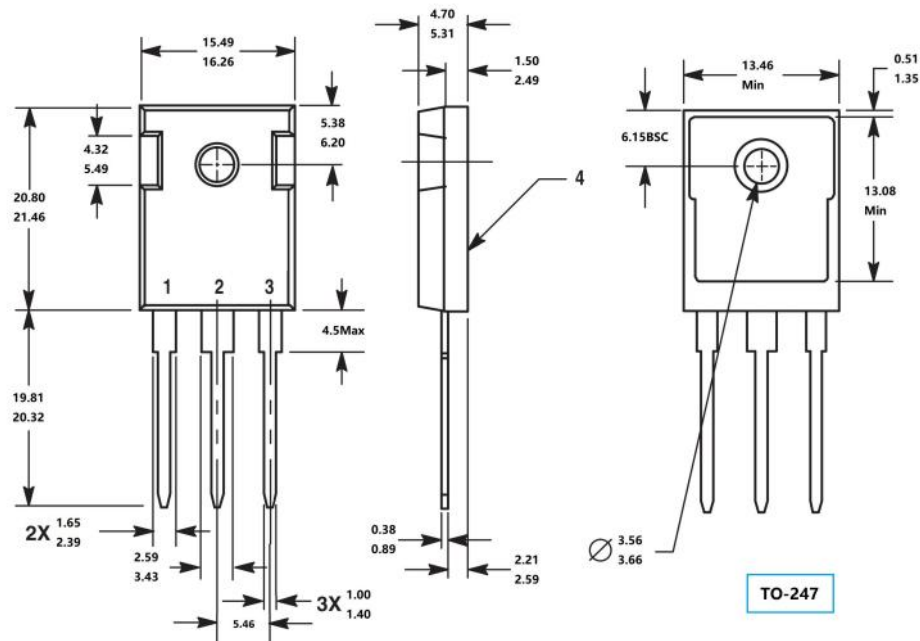
**Maximum Drain Current
vs. Case Temperature**

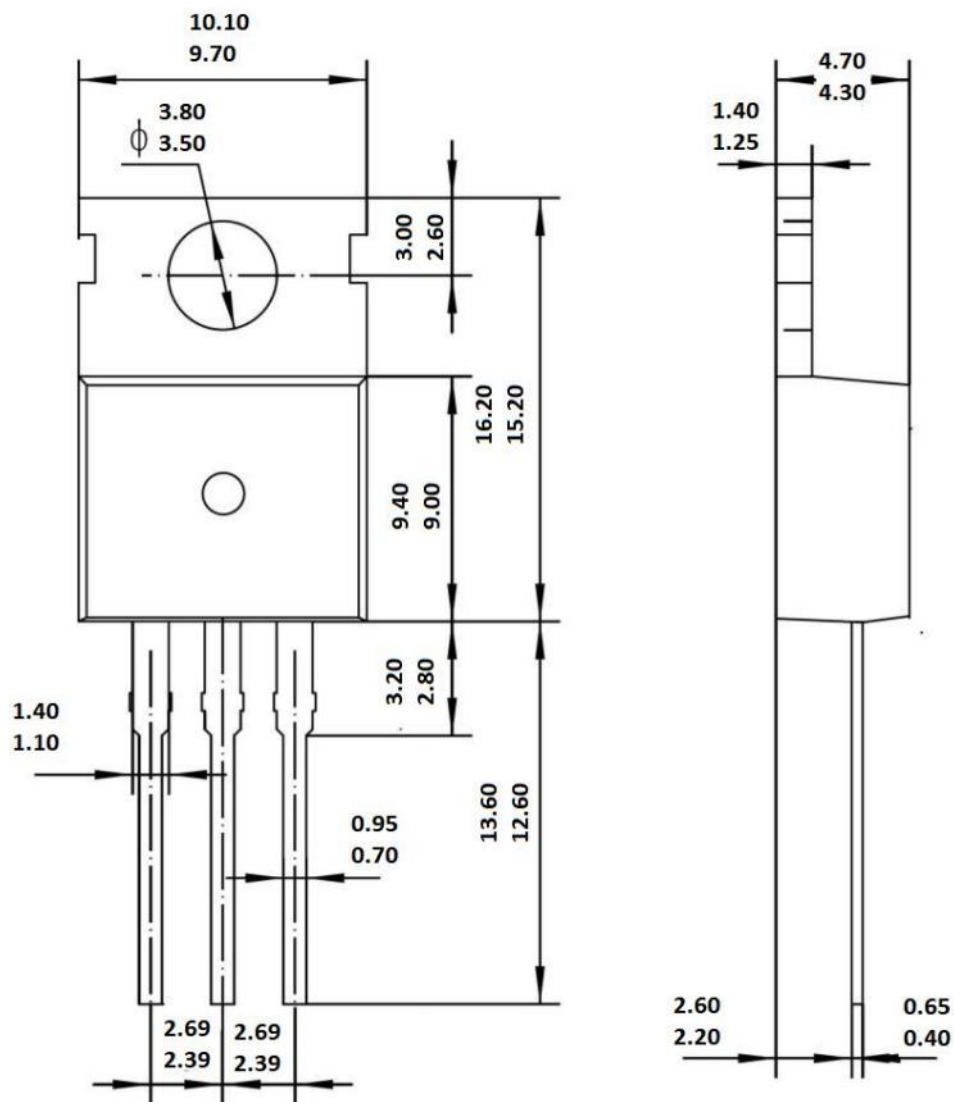


Transient Thermal Resposn Curve



PACKAGE MECHANICAL DATA





TO-220

Unit: mm

